

Sensor on Wafer

Capella Series [T/C/P]

Sensor wafer system for semiconductor process diagnosis

2024 BINE SYSTEMS CO., LTD



Product Series

Code NO.	Model	Temp range (°C)	Plasma	Description	Naming	
А	LT-300	20~140	None	Low Temp		
В	LTP-300	20~140	Apply	Low Temp		
С	CY-300	-40~140	None	Cryonenic Temp		
D	CYP-300	-40~140	Apply	Cryonenic Temp	Customer Use Temp	
E	HT-300	20~160	None	High Temp	-	
F	HTP-300	20~160	Apply	High Temp		



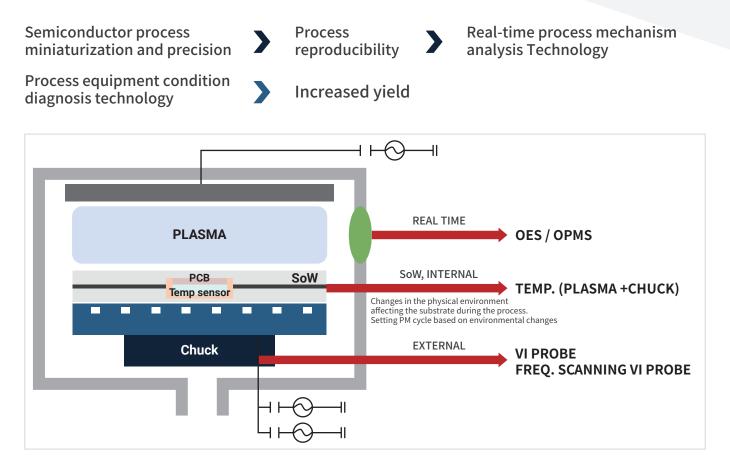
Product necessity

300mm Etcher

It is an important product for securing price competitiveness in semiconductors and developing cutting-edge technologies for future semiconductors by periodically monitoring the status of process equipment, converting it into big data, and optimizing equipment inspection costs through deep learning.

- Check chamber status diagnosis using SoW
- Equipment maintenance optimization
- Increase semiconductor output
- Strengthen price competitiveness

Area of using SoW products



Custom diagnostic system



Manufacturing and development capabilities

Possessing dedicated Fab facilities, equipment & analysis systems for the development and production of 300mm wafer type sensors

- Development and know-how for wafer-type sensors
- Holds numerous patents essential for the development of various wafer-type sensors



SoW Product

SOW	SINGLE STATION	FOUP	UI						
Wafer type sensor Ass'y	Cradle dedicated to SoW utilization	Cassette for SoW utilization in process equipment	Dedicated program for utilizing SoW						
etween top and bottom lere is a built-in sensor ircuit- sensor, driving element, lemory, battery, wireless ansmission, reception and harging antena, etc.	Wireless data transmission and reception and wireless charging function	Wireless data transmission and reception and wireless charging function	SoW status monitoring, various settings of parameter values, Sending/receiving measurement data and implementing charts						
Wafer Wafer Mathesive fixation Wafer Mathesive fixation Single Station storage Before after of wafer using Sensor storage and the maintation of charging condition Sensor storage and the maintation of Compared the maintation of									

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Reliability performance test

Reliability test : Etcher system

System : ICP-RIE etcher RF Power : 4.5kW (Source) / 4 kW (Bias) Plasma "ON" time : 180 sec

Conditions	4.0kw / 4.5kw. 180 sec, 5 times						
NO.	1st	2nd	3rd	4th	5th		
Range	38 <u>.</u> 26	38.41	38.50	38.38	38 <u>.</u> 41		
Max	86 <u>.</u> 82	87 <u>.</u> 07	87 <u>.</u> 27	86.58	86 <u>.</u> 58		
Min	48.56	48.66	48 <u>.</u> 77	48.20	48 <u>.</u> 17		
Ave	64.45	64 <u>.</u> 36	64.74	64.42	64 <u>.</u> 32		
3-Sigma	12 <u>.</u> 21	12 <u>.</u> 07	12 <u>.</u> 27	11 <u>.</u> 98	11 <u>.</u> 90		

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A REAL PROPERTY.



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